Sheet 1 of 1 Docket No. Serial No. 37 CFR 1.501 09792909-5657. 10/645,805 INFORMATION DISCLOSURE STATEMENT Applicants: IN A PATENT Dharam Pal Gosain (use several sheets if necessary) Filing Date Group Art Unit August 21, 2003 2813 U.S. PATENT DOCUMENTS Filing Date Examiner's Class Subclass · If appropriate Initials • **Document Number** Date Country AA AB AC ΑD ΑĒ ΑF AG FOREIGN PATENT DOCUMENTS : . Translation Date Country . Class Subclass Document Number Yes No AH AL \$ AJ ΑK AL AM AN AO AP AQ AŔ ·AS AT OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.) Australian Search Report Unavailable

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*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through

citation if not in conformance and not considered. Include copy of this form with next communication to applicant.